In the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. - 3. (Cancelled)

- 4. (Previously presented) A thin film magnetic head according to Claim 30, wherein the Young's modulus E of the gap layer is $E \ge 127.4$ (GPa).
- 5. (Previously presented) A thin film magnetic head according to Claim 29, wherein the atomic ratio of N of the SiON film is 1 (at%) \leq N atomic % \leq 6 (at%).

6.-7. (Cancelled)

8. (Previously presented) A thin film magnetic head comprising:
a magnetoresistive element capable of detecting a recording signal
due to a change in electric resistance with an external magnetic field; and
shield layers formed above and below the magnetoresistive
element with gap layers provided therebetween,

wherein the cores have a facing surface,
wherein at least one of the gap layers comprises a SiON film
having a Young's modulus E where E > 123.2 (GPa).

9. (Cancelled)

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- 10. (Previously presented) A thin film magnetic head according to Claim 8, wherein the atomic ratio of N of the SiON film is 0 (at%) < N atomic % \leq 6 (at%).
- 11. (Previously presented) A thin film magnetic head according to Claim 8, wherein the Young's modulus E of the at least one gap layer is $E \ge 127.4$ (GPa).
- 12. (Previously presented) A thin film magnetic head according to Claim 11, wherein the atomic ratio of N of the SiON film is 1 (at%) \leq N atomic % \leq 6 (at%).
 - 13. 28. (Cancelled)
- 29. (Previously presented) A thin film magnetic head comprising:
 a gap layer provided between cores made of a magnetic material;
 and
- a coil for inducing a recording magnetic field in the cores, wherein the gap layer comprises a SiON film, the atomic ratio of N of the SiON film being 0 (at%) < N atomic % \leq 6 (at%).
- 30. (Previously presented) A thin film magnetic head according to Claim 29, wherein the Young's modulus E of the gap layer is E > 123.2 (GPa).
 - 31. 44. (Cancelled)